ASSP For Power Management Applications (General Purpose DC/DC Converter)

2-ch DC/DC Converter IC

with Overcurrent Protection

MB39A104

■ DESCRIPTION

The MB39A104 is a 2-channel DC/DC converter IC using pulse width modulation (PWM), incorporating an overcurrent protection circuit (requiring no current sense resistor). This IC is ideal for down conversion.

Operating at high frequency reduces the value of coil.

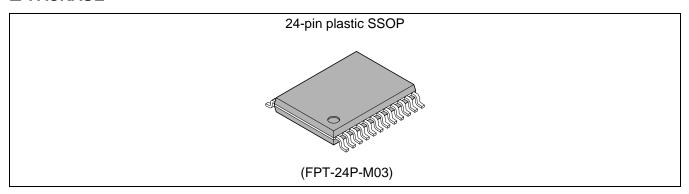
This is ideal for built-in power supply such as LCD monitors and ADSL.

This product is covered by US Patent Number 6,147,477.

■ FEATURES

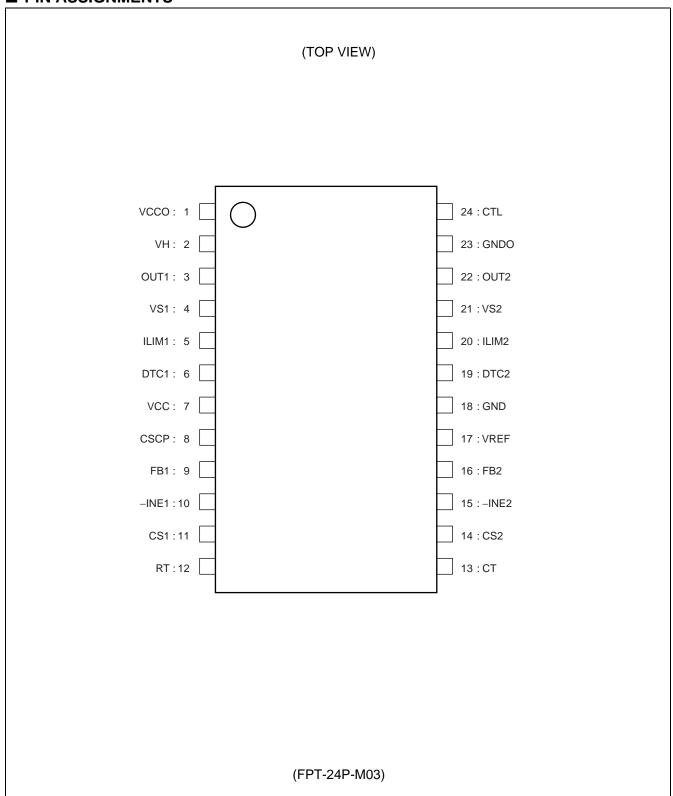
- Built-in timer-latch overcurrent protection circuit (requiring no current sense resistor)
- Power supply voltage range: 7 V to 19 V
- Reference voltage : 5.0 V \pm 1 %
- Error amplifier threshold voltage : 1.24 V \pm 1 %
- High-frequency operation capability: 1.5 MHz (Max)
- Built-in standby function: 0 μA (Typ)
- Built-in soft-start circuit independent of loads
- Built-in totem-pole type output for Pch MOS FET

■ PACKAGE





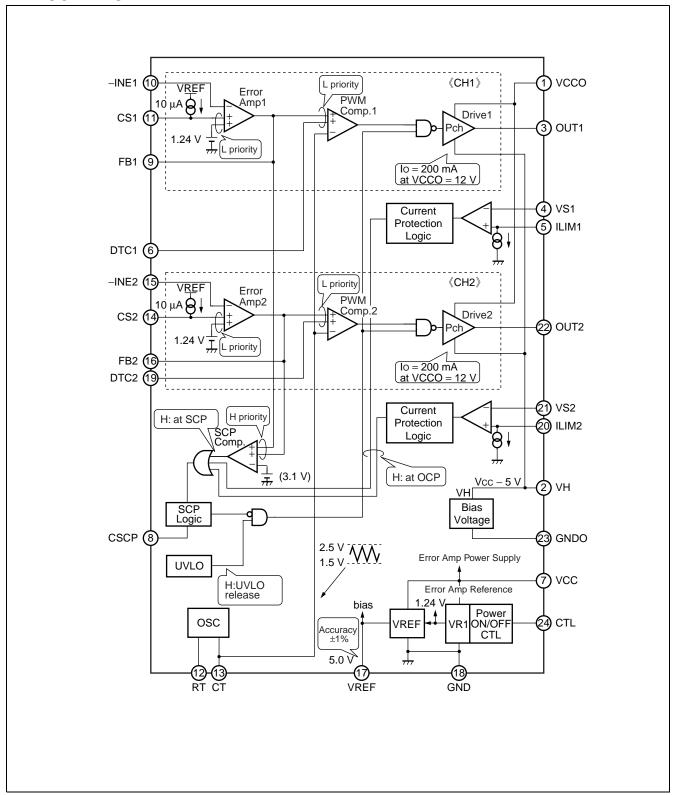
■ PIN ASSIGNMENTS



■ PIN DESCRIPTION

Pin No.	Symbol	I/O	Descriptions		
1	VCCO		Output circuit power supply terminal (Connect to same potential as VCC pir		
2	VH	0	Power supply terminal for FET drive circuit (VH = Vcc - 5 V)		
3	OUT1	0	External Pch MOS FET gate drive terminal		
4	VS1	I	Overcurrent protection circuit input terminal		
5	ILIM1	I	Overcurrent protection circuit detection resistor connection terminal. Set overcurrent detection reference voltage depending on external resistor and internal current resource (110 μA at RT = 24 $k\Omega)$		
6	DTC1	I	PWM comparator block (PWM) input terminal. Compares the lowest voltage among FB1 and DTC terminals with triangular wave and controls output.		
7	VCC		Power supply terminal for reference power supply and control circuit (Connect to same potential as the VCCO terminal)		
8	CSCP		Timer-latch short-circuit protection capacitor connection terminal		
9	FB1	0	Error amplifier (Error Amp 1) output terminal		
10	-INE1	I	Error amplifier (Error Amp 1) inverted input terminal		
11	CS1		Soft-start capacitor connection terminal		
12	RT	_	Triangular wave oscillation frequency setting resistor connection terminal		
13	СТ	_	Triangular wave oscillation frequency setting capacitor connection terminal		
14	CS2		Soft-start capacitor connection terminal		
15	-INE2	I	Error amplifier (Error Amp 2) inverted input terminal		
16	FB2	0	Error amplifier (Error Amp 2) output terminal		
17	VREF	0	Reference voltage output terminal		
18	GND	_	Output circuit ground terminal (Connect to same potential as GNDO terminal.)		
19	DTC2	I	PWM comparator block (PWM) input terminal. Compares the lowest voltage among FB2 and DTC terminals with triangular wave and controls output.		
20	ILIM2	I	Overcurrent protection circit detection resistor connection terminal. Set overcurrent detection reference voltage depending on external resistor and internal current resource (110 μA at RT = 24 $k\Omega)$		
21	VS2	I	Overcurrent protection circuit input terminal		
22	OUT2	0	External Pch MOS FET gate drive terminal		
23	GNDO		Output circuit ground terminal (Connect to same potential as GND terminal.)		
24	CTL	I	Power supply control terminal. Setting the CTL terminal at "L" level places IC in the standby mode.		

■ BLOCK DIAGRAM



■ ABSOLUTE MAXIMUM RATINGS

Parameter	Symbol	Condition	Rat	Unit	
Farameter	Syllibol	Condition	Min	Max	Oilit
Power supply voltage	Vcc	VCC, VCCO terminal	_	20	V
Output current	lo	OUT1, OUT2 terminal		60	mA
Output peak current	Іор	$Duty \le 5\% \ (t = 1/fosc \times Duty)$		700	mA
Power dissipation	Po	Ta ≤ +25 °C		740*	mW
Storage temperature	Тѕтс	_	–55	+125	°C

^{*:} The packages are mounted on the epoxy board (10 cm \times 10 cm).

WARNING: Semiconductor devices can be permanently damaged by application of stress (voltage, current, temperature, etc.) in excess of absolute maximum ratings. Do not exceed these ratings.

■ RECOMMENDED OPERATING CONDITIONS

Parameter	Cumbal	Condition		Unit		
Parameter	Symbol	Condition	Min	Тур	Max	Unit
Power supply voltage	Vcc	VCC, VCCO terminal	7	12	19	V
Reference voltage output current	IREF	VREF terminal	-1	_	0	mA
VH output current	Ivн	VH terminal	0	_	30	mA
Input voltage	VINE	-INE1, -INE2 terminal	0	_	Vcc - 0.9	V
Imput voitage	VDTC	DTC1, DTC2 terminal	0	_	Vcc - 0.9	V
Control input voltage	Vctl	CTL terminal	0	_	19	V
Output current	lo	OUT1, OUT2 terminal	-45	_	+45	mA
Output Peak current	Іор	$Duty \le 5\% \ (t = 1/fosc \times Duty)$	-450	_	+450	mA
Oscillation frequency	fosc	Overcurrent detection by ON resistance of FET	100	500	1000	kHz
		*	100	500	1500	kHz
Timing capacitor	Ст	_	39	100	560	рF
Timing resistor	Rт	_	11	24	130	kΩ
VH terminal capacitor	Сун	VH terminal	_	0.1	1.0	μF
Soft-start capacitor	Cs	CS1, CS2 terminal	_	0.1	1.0	μF
Short-circuit detection capacitor	Cscp	CSCP terminal	_	0.1	1.0	μF
Reference voltage output capacitor	Cref	VREF terminal	_	0.1	1.0	μF
Operating ambient temperature	Та	_	-30	+25	+85	°C

^{*:} See" ■ SETTING THE TRIANGULAR OSCILLATION FREQUENCY".

WARNING: The recommended operating conditions are required in order to ensure the normal operation of the semiconductor device. All of the device's electrical characteristics are warranted when the device is operated within these ranges.

Always use semiconductor devices within their recommended operating condition ranges. Operation outside these ranges may adversely affect reliability and could result in device failure.

No warranty is made with respect to uses, operating conditions, or combinations not represented on the data sheet. Users considering application outside the listed conditions are advised to contact their FUJITSU representatives beforehand.

■ ELECTRICAL CHARACTERISTICS

(VCC = VCCO = 12 V, VREF = 0 mA, Ta = +25 °C)

Development			D'o No	(VCC = VCCO = 12 \		Value	<u>, </u>	11:0:4
Parameter Output voltage		Symbol	Pin No	Conditions	Min Typ		Max	Unit
		V _{REF}	17	Ta = +25 °C	4.95	5.00	5.05	V
1.Reference voltage block [REF]	Output voltage temperature variation	ΔV _{REF} / V _{REF}	17	Ta = 0 °C to +85 °C	_	0.5*	_	%
tefe olta ck [Input stability	Line	17	VCC = 7 V to 19 V	_	3	10	mV
H od	Load stability	Load	17	VREF = 0 mA to -1 mA	_	1	10	mV
	Short-cuircuit output current	los	17	VREF = 1 V	-50	-25	-12	mA
2.Under voltage lockout protection circuit block [UVLO]	Threshold	VTLH	17	VREF =	2.6	2.8	3.0	V
2.Under age lock ection cir ock [UVL	voltage	VTHL	17	VREF = Y	2.4	2.6	2.8	V
volta prote bloc	Hysteresis width	Vн	17	_	_	0.2 *	_	V
ircuit block igic]	Threshold voltage	V _{тн}	8	_	0.68	0.73	0.78	V
3.Short-circuit detection block [SCP Logic]	Input source current	Icscp	8	_	-1.4	-1.0	-0.6	μΑ
3.8 dete	Reset voltage	V _{RST}	17	VREF = 7	2.4	2.6	2.8	V
4.Short-circuit detection block [SCP Comp]	Threshold voltage	Vтн	8	_	2.8	3.1	3.4	V
gular cillator DSC]	Oscillation frequency	fosc	13	$CT = 100 \text{ pF}, RT = 24 \text{ k}\Omega$	450	500	550	kHz
5.Triangular wave oscillator block [OSC]	Frequency temperature variation	Δfosc/ fosc	13	Ta = 0 °C to +85 °C	—	1*		%
6.Soft- start block [CS1, CS2]	Charge current	Ics	11, 14	CS1 = CS2 = 0 V	-14	-10	-6	μА
olifier p1, p2]	Threshold voltage	Vтн	9, 16	FB1 = FB2 = 2 V	1.227	1.240	1.253	V
7.Error amplifier bolck [Error Amp1, Error Amp2]	Input bias current	Ів	10, 15	-INE1 = -INE2 = 0 V	-120	-30	_	nA
7.Err [Err Err	Voltage gain	Av	9, 16	DC	_	100*	_	dB

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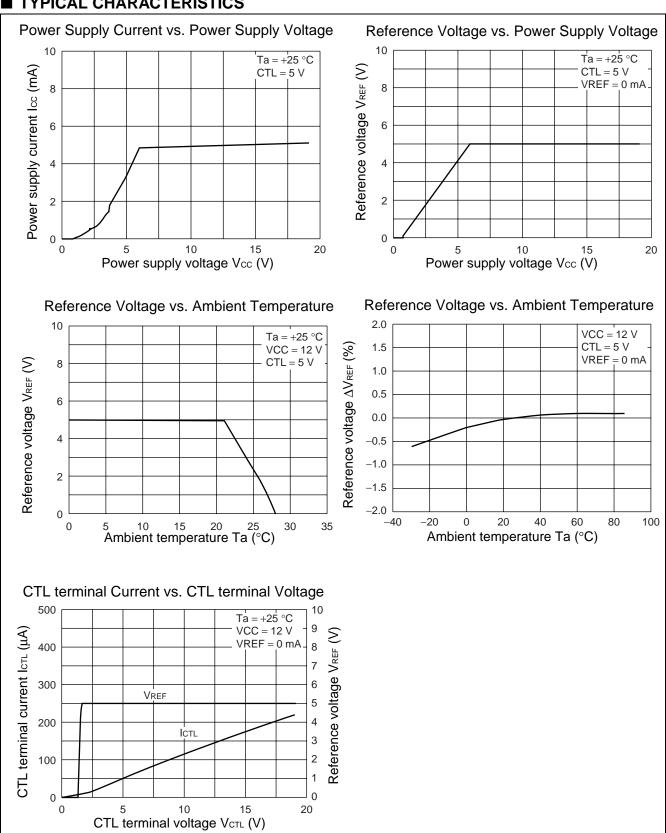
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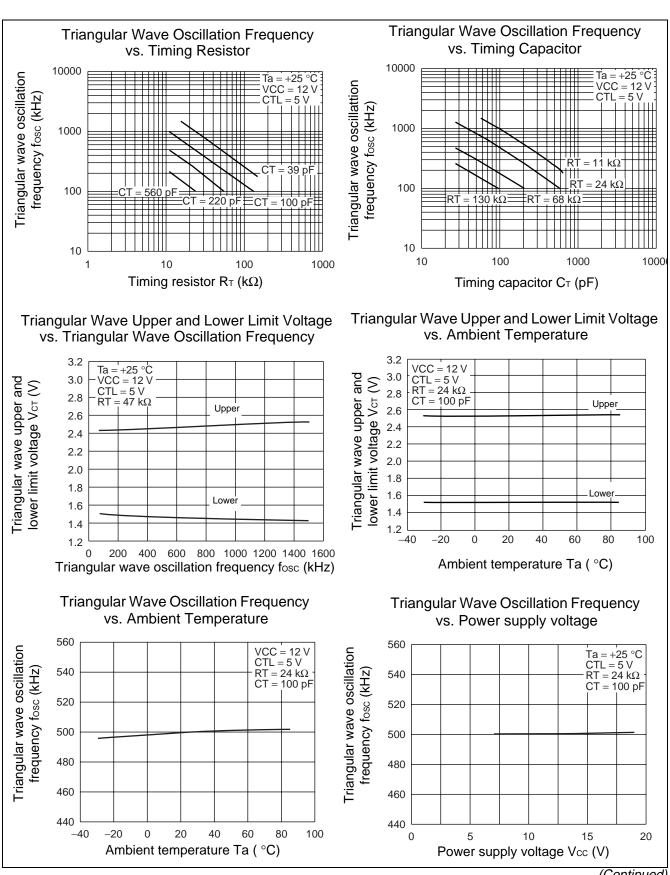
(VCC = VCCO = 12 V, VREF = 0 mA, Ta = +25 °C)

Davamate:		Come le sal	Dia N	Conditions	Value			
Parameter		Symbol	Pin No.	Conditions	Min	Тур	Max	Unit
bolck j	Frequency bandwidth		9, 16	$A_V = 0 dB$		1.6*		MHz
fier np1 np2	Output voltage	Vон	9, 16	_	4.7	4.9	_	V
mpli or Ar	Output voltage	Vol	9, 16	_		40	200	mV
8.Error amplifier bolck [Error Amp1, Error Amp2]	Output source current	Isource	9, 16	FB1 = FB2 = 2 V		-2	-1	mA
8.	Output sink current	İsink	9, 16	FB1 = FB2 = 2 V	150	200		μΑ
arator p.1, o.2]	Threshold voltage	Vто	6, 19	Duty cycle = 0 %	1.4	1.5		V
PWM comparate block [PWM Comp.1, PWM Comp.2]	Triiconoid voitage	V _{T100}	6, 19	Duty cycle = Dtr	_	2.5	2.6	V
9.PWM comparator block [PWM Comp.1, PWM Comp.2]	Input current	Іотс	6, 19	DTC1 = DTC2 = 0.4 V	-2.0	-0.6		μА
urrent circuit c CP2]	ILIM terminal input current	Ішм	5, 20	$RT = 24 \text{ k}\Omega$, $CT = 100 \text{ pF}$	99	110	121	μА
10.0 Vercurrent protection circuit plock CP1, OCP2 COCP1, OCP2 Coccurrent Coc		Vıo	5, 20	_	_	1*	_	mV
11.Bias voltage block [VH]	Output voltage	Vн	2	VCC = VCCO = 7 V to 19 V VH = 0 mA to 30 mA	Vcc- 5.5	Vcc- 5.0	Vcc- 4.5	V
	Output source current	Isource	3, 22	OUT1 to OUT4 = 7 V, Duty ≤ 5 % (t = 1/fosc×Duty)	_	-300	_	mA
12.Output block [Drive1, Drive2]	Output sink current	İsink	3, 22	OUT1 to OUT4 = 12 V, Duty ≤ 5 % (t = 1/fosc×Duty)		350		mA
12 C	Output ON	Rон	3, 22	OUT1 = OUT2 = -45 mA		8.0	12.0	Ω
	resistor	Rol	3, 22	OUT1 = OUT2 = 45 mA	_	6.5	9.7	Ω
충	CTL input voltage	VIH	24	IC Active mode	2	_	19	V
	OTE input voltage	VIL	24	IC Standby mode	0		0.8	V
ontrol I [CTL]		Істьн	24	CTL = 5 V	_	50	100	μΑ
13.Control block [CTL]	Input current	Істьь	24	CTL = 0 V	_	_	1	μА
eral	Standby current	Iccs	1, 17	CTL = 0 V		0	10	μΑ
14.General	Power supply current	Icc	1, 17	CTL = 5 V		4.0	6.0	mA

^{*:} Standard design value.

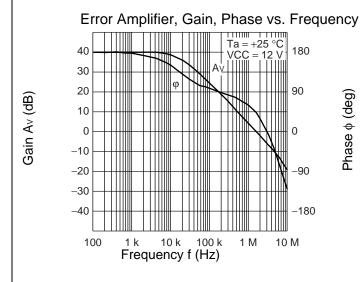
■ TYPICAL CHARACTERISTICS

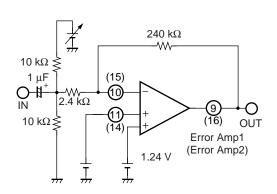




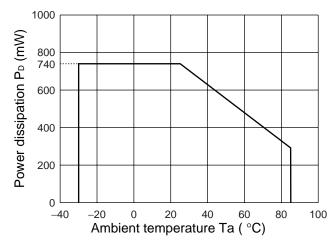
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Power Dissipation vs. Ambient Temperature



■ FUNCTIONS

1. DC/DC Converter Functions

(1) Reference voltage block (REF)

The reference voltage circuit generates a temperature-compensated reference voltage (5.0 V Typ) from the voltage supplied from the power supply terminal (pin 7). The voltage is used as the reference voltage for the IC's internal circuitry.

The reference voltage can supply a load current of up to 1 mA to an external device through the VREF terminal (pin 17).

(2) Triangular-wave oscillator block (OSC)

The triangular wave oscillator incorporates a timing capacitor and a timing resistor connected respectively to the CT terminal (pin 13) and RT terminal (pin 12) to generate triangular oscillation waveform amplitude of 1.5 V to 2.5 V.

The triangular waveforms are input to the PWM comparator in the IC.

(3) Error amplifier block (Error Amp1, Error Amp2)

The error amplifier detects the DC/DC converter output voltage and outputs PWM control signals. In addition, an arbitrary loop gain can be set by connecting a feedback resistor and capacitor from the output terminal to inverted input terminal of the error amplifier, enabling stable phase compensation to the system.

Also, it is possible to prevent rush current at power supply start-up by connecting a soft-start capacitor with the CS1 terminal (pin 11) and CS2 terminal (pin 14) which are the non-inverted input terminal for Error Amp. The use of Error Amp for soft-start detection makes it possible for a system to operate on a fixed soft-start time that is independent of the output load on the DC/DC converter.

(4) PWM comparator block (PWM Comp.)

The PWM comparator is a voltage-to-pulse width modulator that controls the output duty depending on the input/output voltage.

The comparator keeps output transistor on while the error amplifier output voltage remain higher than the triangular wave voltage.

(5) Output block

The output block is in the totem pole configuration, capable of driving an external P-channel MOS FET.

(6) Bias voltage block (VH)

This bias voltage circuit outputs Vcc - 5 V(Typ) as minimum potential of the output circuit. In standby mode, this circuit outputs the potential equal to Vcc.

2. Control Function

When CTL terminal (pin 24) is "L" level, IC becomes the standby mode. The power supply current is 10 μ A (Max) at the standby mode.

CTL	Power
L	OFF (Standby)
Н	ON (Operating)

3. Protective Functions

(1) Timer-latch overcurrent protection circuit block (OCP)

The timer-latch overcurrent protection circuit is actuated upon completion of the soft-start period. When an overcurrent flows, the circuit detects the increase in the voltage between the FET's drain and source using the external FET ON resistor, actuates the timer circuit, and starts charging the capacitor C_{SCP} con-nected to the CSCP terminal (pin 8). If the overcurrent remains flowing beyond the predetermined period of time, latch is set and OUT terminlas (pin 3,22) of each channel are fixed at "H" level. And the circuit sets the latch to turn off the external FET. The detection current value can be set by resistor R_{LIM1} connected between the FET's drain and the ILIM1 terminal (pin 5) and resistor R_{LIM2} connected between the drain and the ILIM2 terminal (pin 20).

Changing connection enables to detect overcurrent at current sense resistor.

To reset the actuated protection circuit, either the power supply turn off and on again or set the CTL terminal (pin 6) to the "L" level to lower the VREF terminal (pin 17) voltage to 2.4 V (Min) or less. (See "1. Setting Timer-Latch Overcurrent Protection Detection Current" in "■ABOUT TIMER-LATCH PROTECTION CIRCUIT".)

(2) Timer-latch short-circuit protection circuit (SCP Logic, SCP Comp.)

The short-circuit detection comparator (SCP Comp.) detects the output voltage level of Error Amp, and if the error amp output voltage of any channel falls below the short-circuit detection voltage (3.1 V Typ), the timer circuits are actuated to start charging the external capacitor C_{SCP} connected to the CSCP terminal (pin 8). When the capacitor voltage reaches about 0.73 V, the circuit is turned off the output transistor and sets the dead time to 100 %.

To reset the actuated protection circuit, either the power supply turn off and on again or set the CTL terminal (pin 24) to the "L" level to lower the VREF terminal (pin 17) voltage to 2.4 V (Min) or less. (See "2. Setting Time Constant for Timer-Latch Short-Circuit Protection Circuit" in "■ABOUT TIMER-LATCH PROTECTION CIRCUIT".)

(3) Under voltage lockout protection circuit (UVLO)

The transient state or a momentary decrease in supply voltage, which occurs when the power supply is turned on, may cause the IC to malfunction, resulting in breakdown or degradation of the system. To prevent such malfunctions, under voltage lockout protection circuit detects a decrease in internal reference voltage with respect to the power supply voltage, turns off the output transistor, and sets the dead time to 100% while holding the CSCP terminal (pin 8) at the "L" level.

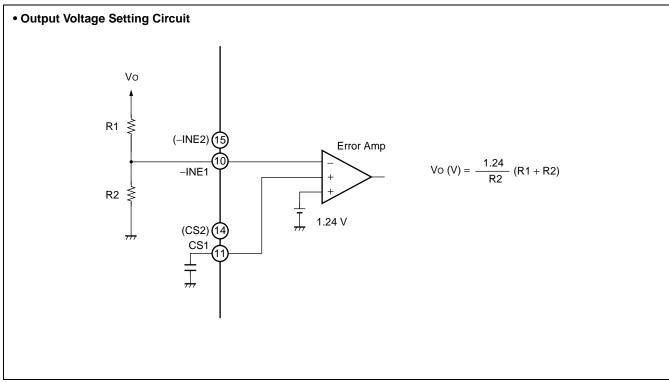
The circuit restores the output transistor to normal when the supply voltage reaches the threshold voltage of the undervoltage lockout protection circuit.

(4) Protection circuit operating function table

This table refers to output condition when protection circuit is operating.

Operating circuit	CS1	CS2	OUT1	OUT2
Overcurrent protection circuit	L	L	Н	Н
Short-circuit protection circuit	L	L	Н	Н
Under-voltage lockout	L	L	Н	Н

■ SETTING THE OUTPUT VOLTAGE



■ SETTING THE TRIANGULAR OSCILLATION FREQUENCY

The triangular oscillation frequency is determined by the timing capacitor (C_T) connected to the CT terminal (pin 13), and the timing resistor (R_T) connected to the RT terminal (pin 12).

Moreover, it shifts more greatly than the caluculated values according to the constant of timing resistor (R_T) when the triangular wave oscillation frequency exceeds 1 MHz. Therefore, set it referring to "Triangular Wave Oscillation Frequency vs. Timing Resistor" and "Triangular Wave Oscillation Frequency vs. Timing Capacitor" in " \blacksquare TYPICAL CHARACTERISTICS".

Triangular oscillation frequency: fosc

fosc (kHz)
$$\Rightarrow \frac{1200000}{C_{T} (pF) \bullet R_{T} (k\Omega)}$$

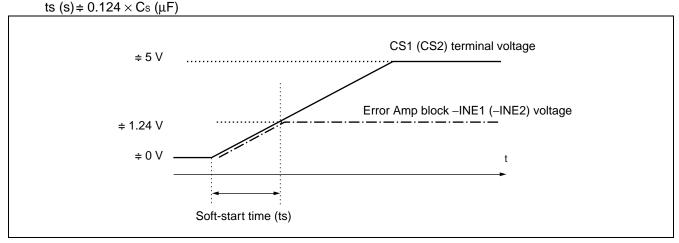
■ SETTING THE SOFT-START AND DISCHARGE TIMES

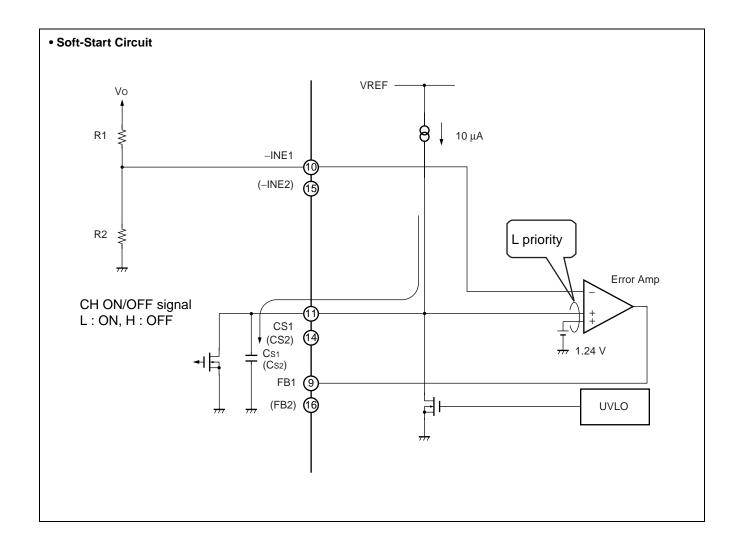
To prevent rush currents when the IC is turned on, you can set a soft-start by connecting soft-start capacitors (C_{S1} and C_{S2}) to the CS1 terminal (pin 11) for channel 1 and the CS2 terminal (pin 14) for channel 2, respectively. When CTL terminal (pin 24) goes to "H" level and IC starts ($V_{CC} \ge UVLO$ threshold voltage), the external soft-start capacitors (C_{S1} and C_{S2}) connected to CS1 and CS2 terminals are charged at 10 μ A. The error amplifier output (FB1 (pin 9) , FB2 (pin 16)) is determined by comparison between the lower one of the potentials at two non-inverted input terminals (1.24 V, CS1 terminal voltages) and the inverted input terminal voltage (–INE1 (pin 10) voltage, –INE2 (pin 15) voltage).

The FB1 (FB2) terminal voltage is decided for the soft-start period by the comparison between 1.24 V in an internal reference voltage and the voltages of the CS1 (CS2) terminal. The DC/DC converter output voltage rises in proportion to the CS1 (CS2) terminal voltage as the soft-start capacitor connected to the CS1 (CS2) terminal is charged.

The soft-start time is obtained from the following formula:

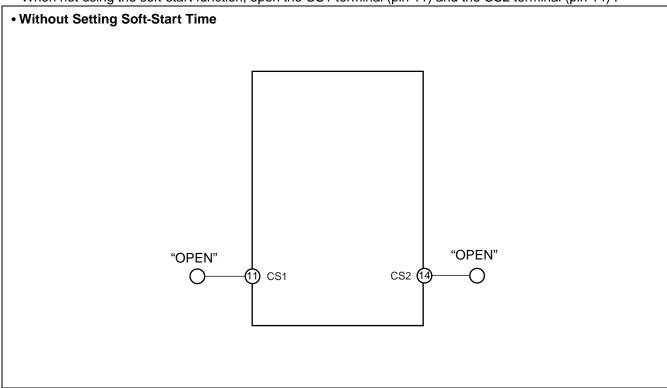
Soft-start time: ts (time to output 100%)





■ TREATMENT WITHOUT USING CS TERMINAL

When not using the soft-start function, open the CS1 terminal (pin 11) and the CS2 terminal (pin 14) .



■ ABOUT TIMER-LATCH PROTECTION CIRCUIT

1. Setting Timer-Latch Overcurrent Protection Detection Current

The overcurrent protection circuit is actuated upon completion of the soft-start period. When an overcurrent flows, the circuit detects the increase in the voltage between the FET's drain and source using the external FET ON resistor (RoN), actuates the timer circuit, and starts charging the capacitor CscP connected to the CSCP terminal (pin 8). If the overcurrent remains flowing beyond the predetermined period of time, the circuit sets the latch to fix OUT terminals (pin 3, 22) at "H" level and turn off the external FET. The detection current value can be set by the resistors (RLIM1 and RLIM2) connected between the FET's drain and the ILIM1 terminal (pin 5) and between the drain and the ILIM2 terminal (pin 20), respectively.

The internal current (ILIM) can be set by the timing resistor (R_T) connected to the RT terminal (pin 12). Time until activating timer circuit and setting latch is equal to short-circuit detection time in "2. Setting Time Constant for Timer-Latch Short-Circuit Protection Circuit".

Internal current value: ILIM

$$I_{\text{LIM}}(\mu A)
ightharpoons = \frac{2700}{R_{\text{T}}(k\Omega)}$$

Detection current value: IOCP

$$\mathsf{locp} \; (\mathsf{A}) \; \doteq \; \frac{ \; \mathsf{ILIM}(\mathsf{A}) \times \mathsf{RLIM}(\Omega) \;}{\mathsf{Ron} \; (\Omega)} \; - \; \frac{ \; (\mathsf{Vin}(\mathsf{V}) - \mathsf{Vo}(\mathsf{V})) \times \mathsf{Vo}(\mathsf{V}) \;}{2 \times \mathsf{Vin}(\mathsf{V}) \times \mathsf{fosc}(\mathsf{Hz}) \times \mathsf{L}(\mathsf{H})}$$

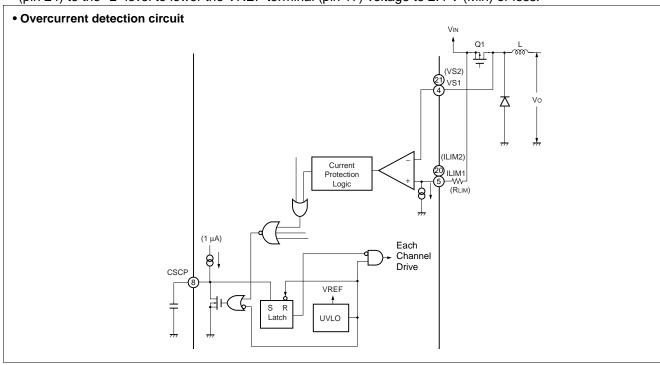
R_{LIM}: Overcurrent detection resistor R_{ON}: External FET ON resistor

V_{IN}: Input voltage

Vo : DC/DC converter output voltage

fosc: Oscillation frequency
L: Coil inductance

To reset the actuated protection circuit, either the power supply turn off and on again or set the CTL terminal (pin 24) to the "L" level to lower the VREF terminal (pin 17) voltage to 2.4 V (Min) or less.



Overcurrent Protection Circuit: Range of Operation

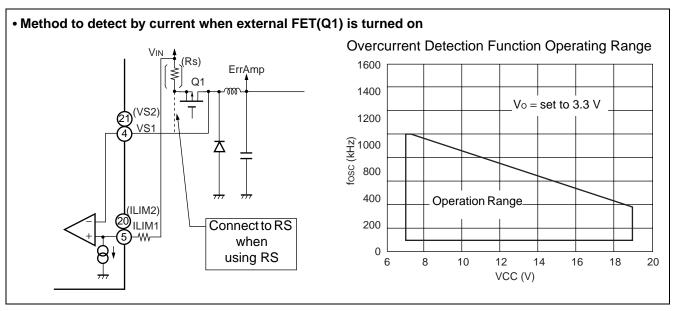
When an overcurrent flow occurs, if the increased voltage between the drain and source of the FET is detected by means of the external FET (Q1) resistor, operational stability is lost when the external FET (Q1) ON interval determined by the oscillation frequency, input voltage, and output voltage falls below 450 ns.

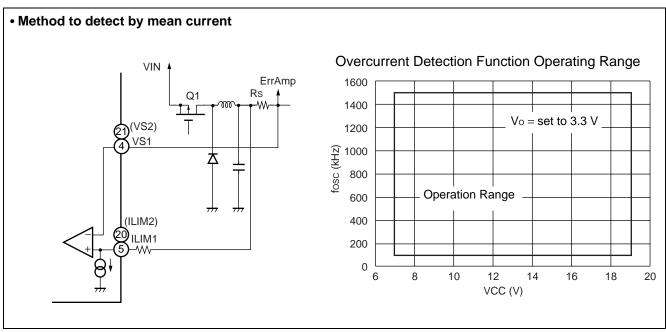
Therefore, the circuit should be used within a range that ensures that the ON interval does not fall below 450ns, according to the following formula.

ON interval 450 (ns)
$$\geq \frac{V_0(V)}{V_{IN}(V) \times fosc(Hz)}$$

If the ON interval of the external FET (Q1) is below 450ns, we recommend the use of an overcurrent detection resistor RS to detect overcurrent, as shown below.

This example shows the range of operation of the overcurrent detection function with a setting of Vo = 3.3V.





2. Setting Time Constant for Timer-Latch Short-Circuit Protection Circuit

Each channel uses the short-circuit detection comparator (SCP Comp.) to always compare the error amplifier's output level to the reference voltage (3.1 V Typ).

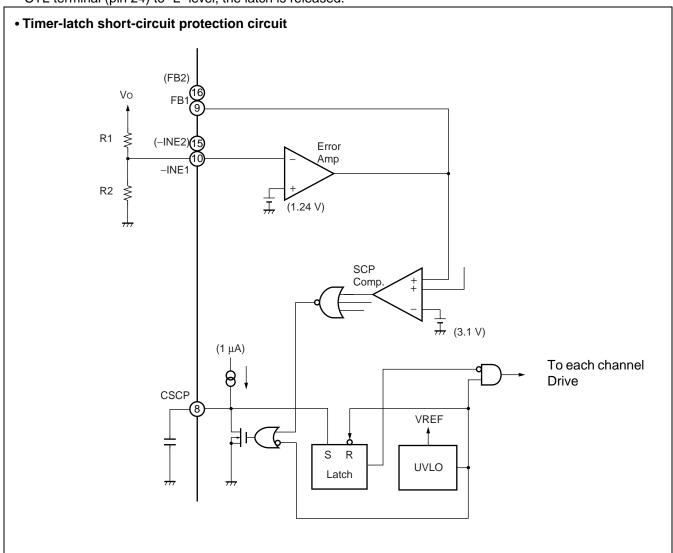
While DC/DC converter load conditions are stable on all channels, the short-circuit detection comparator output remains at "L" level, and the CSCP terminal (pin 8) is held at "L" level.

If the load condition on a channel changes rapidly due to a short-circuit of the load, causing the output voltage to drop, the output of the short-circuit detection comparator goes to "H" level. This causes the external short-circuit protection capacitor C_{SCP} connected to the CSCP terminal to be charged at 1 μ A. Short-circuit detection time (tscp)

$$t_{SCP}$$
 (s) $\neq 0.73 \times C_{SCP}$ (μF)

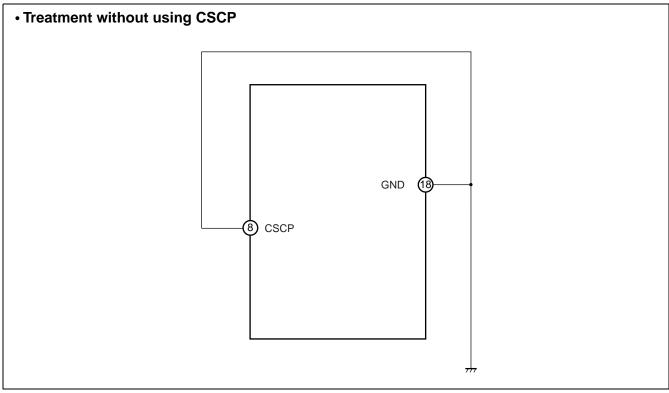
When the capacitor C_{SCP} is charged to the threshold voltage ($V_{TH} \neq 0.73 \text{ V}$), the latch is set and the external FET is turned off (dead time is set to 100%). At this time, the latch input is closed and the CSCP terminal is held at "L" level. If a short-circuit is detected on either of the two channels, both channels are shut off.

When the power supply is turned on back or VREF terminal (pin 17) voltage is less than 2.4 V (Min) by setting CTL terminal (pin 24) to "L" level, the latch is released.



■ TREATMENT WITHOUT USING CSCP TERMINAL

When not using the timer-latch short-circuit protection circuit, connect the CSCP terminal (pin 8) to GND with the shortest distance.

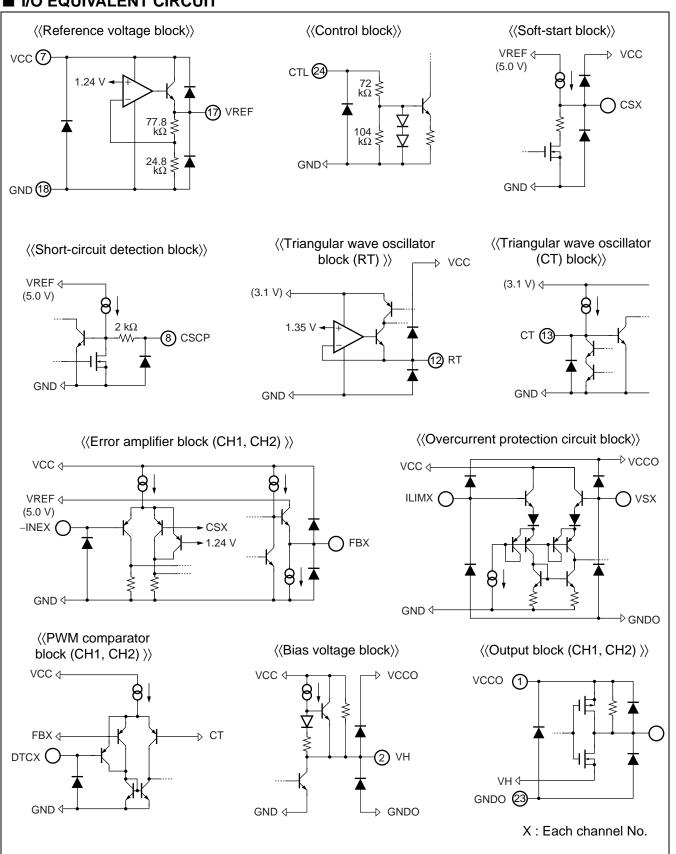


■ RESETTING THE LATCH OF EACH PROTECTION CIRCUIT

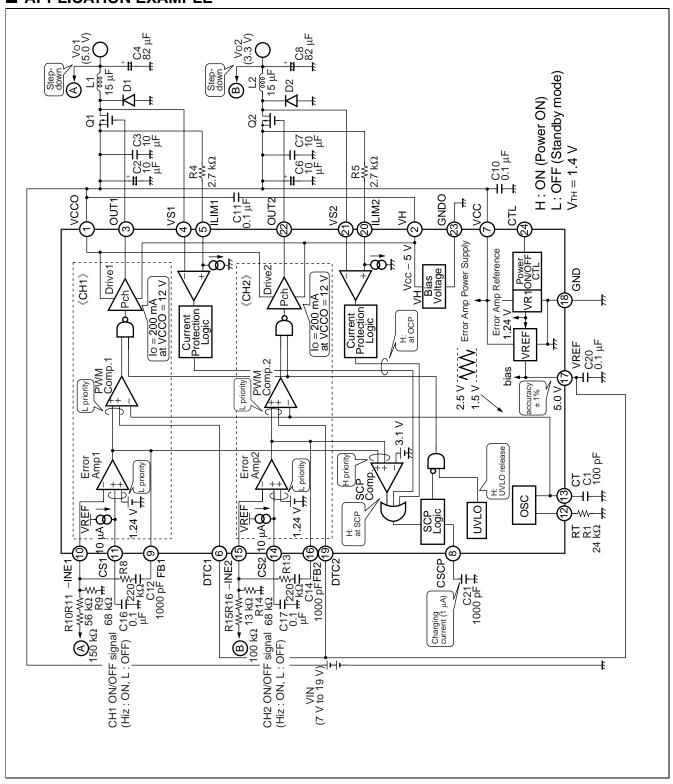
When the overcurrent, or short-circuit protection circuit detects each abnormality, it sets the latch to fix the output at the "L" level.

To reset the actuated protection circuit, either the power supply turn off and on again or set the CTL terminal (pin 24) to the "L" level to lower the VREF terminal (pin 17) voltage to 2.4 V (Min) or less.

■ I/O EQUIVALENT CIRCUIT



■ APPLICATION EXAMPLE



■ PARTS LIST

COMPONENT	ITEM	SPECIF	ICATION	VENDOR	PARTS No.
Q1, Q2	Pch FET	VDS = -30	V, ID = -6 A	TOSHIBA	TPC8102
D1, D2	Diode	VF = 0.42 V (M	ax) , at IF = 3 A	ROHM	RB0530L-30
L1, L2	Inductor	15 μΗ	$3.6~\text{A},50~\text{m}\Omega$	SUMIDA	CDRH104R-150
C1	Ceramics Condenser	100 pF	50 V	TDK	C1608CH1H101J
C2, C6	OS-CON™	10 μF	20 V	SANYO	20SVP10M
C3, C7	Ceramics Condenser	10 μF	25 V	TDK	C3225JF1E106Z
C4, C8	OS-CON™	82 μF	6.3 V	SANYO	6SVP82M
C10, C11, C20	Ceramics Condenser	0.1 μF	50 V	TDK	C1608JB1H104K
C12, C14, C21	Ceramics Condenser	1000 pF	50 V	TDK	C1608JB1H102K
C16, C17	Ceramics Condenser	0.1 μF	50 V	TDK	C1608JB1H104K
R1	Resistor	24 kΩ	0.5 %	ssm	RR0816P-243-D
R4, R5	Resistor	$2.7~\mathrm{k}\Omega$	0.5 %	ssm	RR0816P-272-D
R8, R13	Resistor	220 kΩ	0.5 %	ssm	RR0816P-224-D
R9, R14	Resistor	68 kΩ	0.5 %	ssm	RR0816P-683-D
R10	Resistor	150 k Ω	0.5 %	ssm	RR0816P-154-D
R11	Resistor	56 k $Ω$	0.5 %	ssm	RR0816P-563-D
R15	Resistor	100 kΩ	0.5 %	ssm	RR0816P-104-D
R16	Resistor	13 kΩ	0.5 %	ssm	RR0816P-133-D

Note: TOSHIBA: TOSHIBA Corporation

ROHM: ROHM Co., Ltd

SANYO : SANYO Electric Co., Ltd.

TDK : TDK Corporation

SUMIDA: SUMIDA Electric Co., Ltd.

ssm : SUSUMU Co., Ltd.

■ SELECTION OF COMPONENTS

• Pch MOS FET

The P-ch MOSFET for switching use should be rated for at least 20% more than the maximum input voltage. To minimize continuity loss, use a FET with low R_{DS(ON)} between the drain and source. For high input voltage and high frequency operation, on/off-cycle switching loss will be higher so that power dissipation must be considered. In this application, the Toshiba TPC8102 is used. Continuity loss, on/off switching loss, and total loss are determined by the following formulas. The selection must ensure that peak drain current does not exceed rated values, and also must be in accordance with overcurrent detection levels.

Continuity loss :
$$Pc$$

 $Pc = I_D^2 \times R_{DS (ON)} \times Duty$

$$\begin{array}{c} \text{On-cycle switching loss}: P_{S \, (ON)} \\ P_{S \, (ON)} = \frac{V_{D \, (Max)} \, \times I_{D} \times tr \times fosc}{6} \end{array}$$

$$\begin{aligned} & \text{Off-cycle switching loss}: P_{S \text{ (OFF)}} \\ & P_{S \text{ (OFF)}} = \frac{V_{D \text{ (Max)}} \times I_{D \text{ (Max)}} \times tf \times fosc}{6} \end{aligned}$$

$$P_T = P_C + P_{S(ON)} + P_{S(OFF)}$$

Example: Using the Toshiba TPC8102

CH1

Input voltage $V_{IN\,(Max)}=19\,V$, output voltage $V_0=5\,V$, drain current $I_D=3\,A$, Oscillation frequency fosc = 500 kHz, $L=15\,\mu H$, drain-source on resistance $R_{DS\,(ON)} \doteqdot 50\,m\Omega$, $tr=tf \doteqdot 100\,ns$.

Drain current (Max) : I_{D (Max)}

$$I_{D (Max)} = I_{O} + \frac{V_{IN} - V_{O}}{2L} ton$$

$$= 3 + \frac{19 - 5}{2 \times 15 \times 10^{-6}} \times \frac{1}{500 \times 10^{3}} \times 0.263$$

$$\Rightarrow 3.25 (A)$$

Drain current (Min) : I_{D (Min)}

$$I_{D (Min)} = I_{O} - \frac{V_{IN} - V_{O}}{2L} ton$$

$$= 3 - \frac{19 - 5}{2 \times 15 \times 10^{-6}} \times \frac{1}{500 \times 10^{3}} \times 0.263$$

$$\stackrel{\div}{=} 2.75 \text{ (A)}$$

Pc =
$$lo^{2} \times Ros_{(ON)} \times Duty$$

= $3^{2} \times 0.05 \times 0.263$
 $= 0.118 \text{ W}$

$$P_{S (ON)} = \frac{V_{D (Max)} \times I_{D} \times tr \times fosc}{6}$$

$$= \frac{19 \times 3 \times 100 \times 10^{-9} \times 500 \times 10^{3}}{6}$$

$$\begin{array}{ll} \text{Ps}\,_{(\text{OFF})} & = \frac{V_{\text{D}\,(\text{Max})}\,\times I_{\text{D}\,(\text{Max})}\,\times tf \times fosc}{6} \\ \\ & = \frac{19\times 3.25\times 100\times 10^{-9}\times 500\times 10^{3}}{6} \\ \\ & \div 0.515\,W \end{array}$$

PT = Pc + Ps (ON) + Ps (OFF)

$$\Rightarrow$$
 0.118 + 0.475 + 0.515
 \Rightarrow 1.108 W

The above power dissipation figures for the TPC8102 are satisfied with ample margin at 2.4 W (Ta = \pm 25 °C).

CH2

Input voltage $V_{IN \, (Max)} = 19 \, V$ output voltage $V_O = 3.3 \, V$, drain current $I_D = 3 \, A$, Oscillation frequency fosc = 500 kHz, L = 15 μ H, drain-source on resistance $R_{DS \, (ON)} \doteqdot 50 \, m\Omega$, tr = tf $\doteqdot 100 \, ns$.

Drain current (Max) : I_{D (Max)}

$$I_{D (Max)} = I_O + \frac{V_{IN} - V_O}{2L} ton$$

 $= 3 + \frac{19 - 3.3}{2 \times 15 \times 10^{-6}} \times \frac{1}{500 \times 10^3} \times 0.174$
 $\Rightarrow 3.18 (A)$

Drain current (Min) : I_{D (Min)}
$$I_{D (Min)} = I_{O} - \frac{V_{IN} - V_{O}}{2L} ton$$
$$= 3 - \frac{19 - 3.3}{2 \times 15 \times 10^{-6}} \times \frac{1}{500 \times 10^{3}} \times 0.174$$
$$\Rightarrow \underline{2.82 (A)}$$

$$\begin{array}{ll} \text{Pc} &=& \text{Id} \, ^2 \times \text{Rds} \, (\text{ON}) \times \text{Duty} \\ &=& 3 \, ^2 \times 0.05 \times 0.174 \\ & & \div 0.078 \, W \\ \\ \text{Ps} \, (\text{ON}) &=& \frac{V_{\text{D} \, (\text{Max})} \times \text{Id} \times \text{tr} \times \text{fosc}}{6} \\ &=& \frac{19 \times 3 \times 100 \times 10^{-9} \times 500 \times 10^{3}}{6} \\ & & \div 0.475 \, W \\ \\ \text{Ps} \, (\text{OFF}) &=& \frac{V_{\text{D} \, (\text{Max})} \times \text{Id} \, (\text{Max}) \times \text{tf} \times \text{fosc}}{6} \\ &=& \frac{19 \times 3.18 \times 100 \times 10^{-9} \times 500 \times 10^{3}}{6} \\ & & \div 0.504 \, W \\ \\ \text{PT} &=& \text{Pc} + \text{Ps} \, (\text{ON}) + \text{Ps} \, (\text{OFF}) \\ & & \div 0.078 + 0.475 + 0.504 \\ & & \div 1.057 \, W \\ \end{array}$$

The above power dissipation figures for the TPC8102 are satisfied with ample margin at 2.4 W (Ta = \pm 25 °C).

• Inductors

In selecting inductors, it is of course essential not to apply more current than the rated capacity of the inductor, but also to note that the lower limit for ripple current is a critical point that if reached will cause discontinuous operation and a considerable drop in efficiency. This can be prevented by choosing a higher inductance value, which will enable continuous operation under light loads. Note that if the inductance value is too high, however, direct current resistance (DCR) is increased and this will also reduce efficiency. The inductance must be set at the point where efficiency is greatest.

Note also that the DC superimposition characteristics become worse as the load current value approaches the rated current value of the inductor, so that the inductance value is reduced and ripple current increases, causing loss of efficiency. The selection of rated current value and inductance value will vary depending on where the point of peak efficiency lies with respect to load current.

Inductance values are determined by the following formulas.

The L value for all load current conditions is set so that the peak to peak value of the ripple current is 1/2 the load current or less.

$$\begin{array}{c} Inductance \ value : L \\ L \ \geq \ \frac{2 \ (V_{IN} - V_O)}{I_O} ton \end{array}$$

Example:

L
$$\geq \frac{2 (V_{IN} - V_O)}{I_O}$$
 ton
 $\geq \frac{2 \times (19 - 5)}{I_O} \times \frac{1}{500 \times 10^3} \times 0.263$

$$\begin{array}{ll} L & \geq \frac{2 \; (V_{\text{IN}} - V_{\text{O}})}{I_{\text{O}}} \; \text{ton} \\ \\ & \geq \frac{2 \times \; (19 - 3.3)}{I_{\text{O}}} \times \frac{1}{500 \times 10^{3}} \times 0.174 \end{array}$$

 \geq 3.64 μ H

≥ <u>4.91 µH</u>

Inductance values derived from the above formulas are values that provide sufficient margin for continuous operation at maximum load current, but at which continuous operation is not possible at light loads. It is therefore necessary to determine the load level at which continuous operation becomes possible. In this application, the Sumida CDRH104R-150 is used. At 15 μ H, the load current value under continuous operating conditions is determined by the following formula.

Load current value under continuous operating conditions : lo

$$I_0 \ge \frac{V_0}{2L} toff$$

Example: Using the CDRH104R-150

15 μH (allowable tolerance $\pm 30\%$), rated current = 3.6 A

$$lo \ge \frac{V_0}{2L} toff$$

$$\ge \frac{5}{2 \times 15 \times 10^{-6}} \times \frac{1}{500 \times 10^3} \times (1 - 0.263)$$

≥ <u>245.7 mA</u>

Io
$$\geq \frac{V_0}{2L}$$
 toff
 $\geq \frac{3.3}{2 \times 15 \times 10^{-6}} \times \frac{1}{500 \times 10^3} \times (1 - 0.174)$

≥ <u>181.7 mA</u>

To determine whether the current through the inductor is within rated values, it is necessary to determine the peak value of the ripple current as well as the peak-to-peak values of the ripple current that affect the output ripple voltage. The peak value and peak-to-peak value of the ripple current can be determined by the following formulas.

Peak value : IL

$$I_L \ \geq I_O + \frac{V_{IN} - V_O}{2L} ton$$

Peak-to-peak value : ΔIL

$$\Delta I_{L} \ = \frac{\dot{V}_{\text{IN}} - V_{\text{O}}}{L} ton$$

Example: Using the CDRH104R-150

15 μ H (allowable tolerance $\pm 30\%$), rated current = 3.6 A

Peak value:

CH1

$$\begin{split} I_L & \geq I_O + \frac{V_{IN} - V_O}{2L} ton \\ & \geq 3 + \frac{19 - 5}{2 \times 15 \times 10^{-6}} \times \frac{1}{500 \times 10^3} \times 0.263 \\ & \geq 3.25 \ A \end{split}$$

CH2

$$I_{L} \ge I_{O} + \frac{V_{IN} - V_{O}}{2L} ton$$

$$\ge 3 + \frac{19 - 3.3}{2 \times 15 \times 10^{-6}} \times \frac{1}{500 \times 10^{3}} \times 0.174$$

$$\ge 3.18 \text{ A}$$

Peak-to-peak value:

$$\Delta I_{L} = \frac{V_{IN} - V_{O}}{L} \text{ ton}$$

$$= \frac{19 - 5}{15 \times 10^{-6}} \times \frac{1}{500 \times 10^{3}} \times 0.263$$

$$= 0.491 \text{ A}$$

$$\Delta I_{L} = \frac{V_{IN} - V_{O}}{L} ton$$

$$= \frac{19 - 3.3}{15 \times 10^{-6}} \times \frac{1}{500 \times 10^{3}} \times 0.174$$

$$= 0.364 \text{ A}$$

• Flyback diode

The flyback diode is generally used as a Shottky barrier diode (SBD) when the reverse voltage to the diode is less than 40V. The SBD has the characteristics of higher speed in terms of faster reverse recovery time, and lower forward voltage, and is ideal for achieving high efficiency. As long as the DC reverse voltage is sufficiently higher than the input voltage, the average current flowing through the diode is within the average output current level, and peak current is within peak surge current limits, there is no problem. In this application the Rohm RB053L-30 is used. The diode average current and diode peak current can be calculated by the following formulas.

Diode mean current : IDi

$$I_{Di} \geq I_{O} \times (1 - \frac{V_{O}}{V_{IN}})$$

Diode peak current: IDip

$$I_{Dip} \ge (I_0 + \frac{V_0}{2L} toff)$$

Example: Using the Rohm RB053L-30

VR (DC reverse voltage) = 30 V, average output voltage = 3.0 A, peak surge current = 70 A, VF (forward voltage) = 0.42 V, IF = 3.0 A

CH₁

$$I_Di \ge I_D \times (1 - \frac{V_D}{V_{IN}})$$

$$\geq 3 \times (1 - 0.263)$$

CH2

$$I_{Di} \geq I_{O} \times (1 - \frac{V_{O}}{V_{IN}})$$

$$\geq 3 \times (1 - 0.174)$$

CH1

$$I_{D}ip \geq (I_{O} + \frac{V_{O}}{2L}toff)$$

CH2

$$I_Dip \ge (I_O + \frac{V_O}{2L} toff)$$

• Smoothing Capacitor

The smoothing capacitor is an indispensable element for reducing ripple voltage in output. In selecting a smoothing capacitor it is essential to consider equivalent series resistance (ESR) and allowable ripple current. Higher ESR means higher ripple voltage, so that to reduce ripple voltage it is necessary to select a capacitor with low ESR. However, the use of a capacitor with low ESR can have substantial effects on loop phase characteristics, and therefore requires attention to system stability. Care should also be taken to use a capacity with sufficient margin for allowable ripple current. This application uses the (OS-CON ™) 6SVP82M made by Sanyo. The ESR, capacitance value, and ripple current can be calculated from the following formulas.

Equivalent Series Resistance : ESR

$$\mathsf{ESR} \ \leq \frac{\Delta V_0}{\Delta I_L} - \frac{1}{2\pi f C_L}$$

Capacitance value : CL

$$C_L \ \geq \frac{\Delta I_L}{2\pi f \left(\Delta V_O - \Delta I_L \times ESR\right)}$$

Ripple current : ICLrms

$$IC_{L}rms \geq \frac{(V_{IN} - V_{O}) ton}{2\sqrt{3L}}$$

Example: Using the 6SVP82M

Rated voltage = 6.3 V, ESR = 50 m Ω , maximum allowable ripple current = 1570 mArms

Equivalent series resistance

CH1

$$\begin{split} \text{ESR} & \leq \frac{\Delta V_0}{\Delta I_L} - \frac{1}{2\pi f C_L} \\ & \leq \frac{0.050}{0.491} - \frac{1}{2\pi \times 500 \times 10^3 \times 82 \times 10^{-6}} \end{split}$$

 $\leq 98.0 \text{ m}\Omega$

CH2
ESR
$$\leq \frac{\Delta V_{\text{O}}}{\Delta I_{\text{L}}} - \frac{1}{2\pi f C_{\text{L}}}$$

 $\leq \frac{0.033}{0.364} - \frac{1}{2\pi \times 500 \times 10^{3} \times 82 \times 10^{-6}}$
 $\leq 86.8 \text{ m}\Omega$

Capacitance value

CH1

$$\begin{array}{ll} C_L & \geq \frac{\Delta I_L}{2\pi f \left(\Delta V_O - \Delta I_L \times ESR \right)} \\ & \geq \frac{0.491}{2\pi \times 500 \times 10^3 \times \left(0.050 - 0.491 \times 0.05 \right)} \\ & \geq \underline{6.14 \ \mu E} \end{array}$$

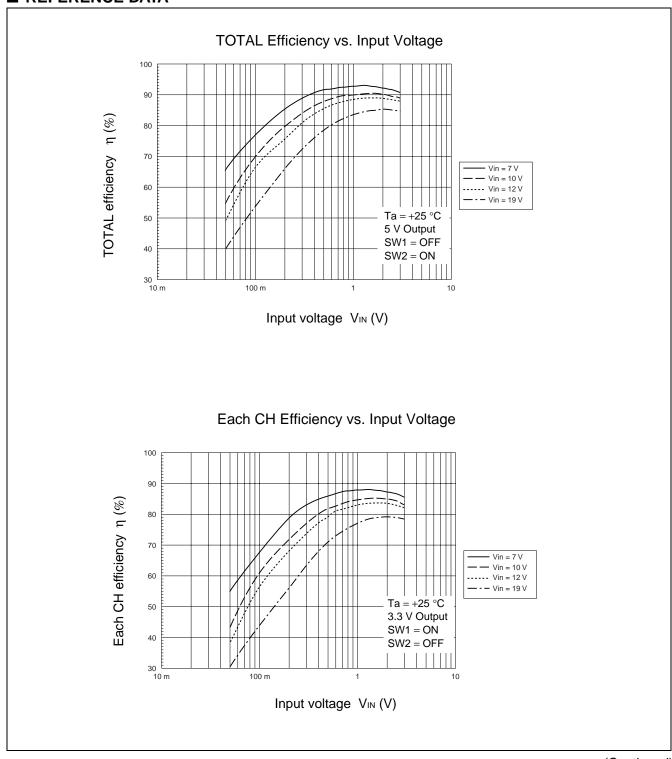
$$\begin{split} C_L & \geq \frac{\Delta I_L}{2\pi f \left(\Delta V_0 - \Delta I_L \times ESR \right)} \\ & \geq \frac{0.364}{2\pi \times 500 \times 10^3 \times \left(0.033 - 0.364 \times 0.05 \right)} \\ & \geq \underline{7.83 \ \mu F} \end{split}$$

Ripple current

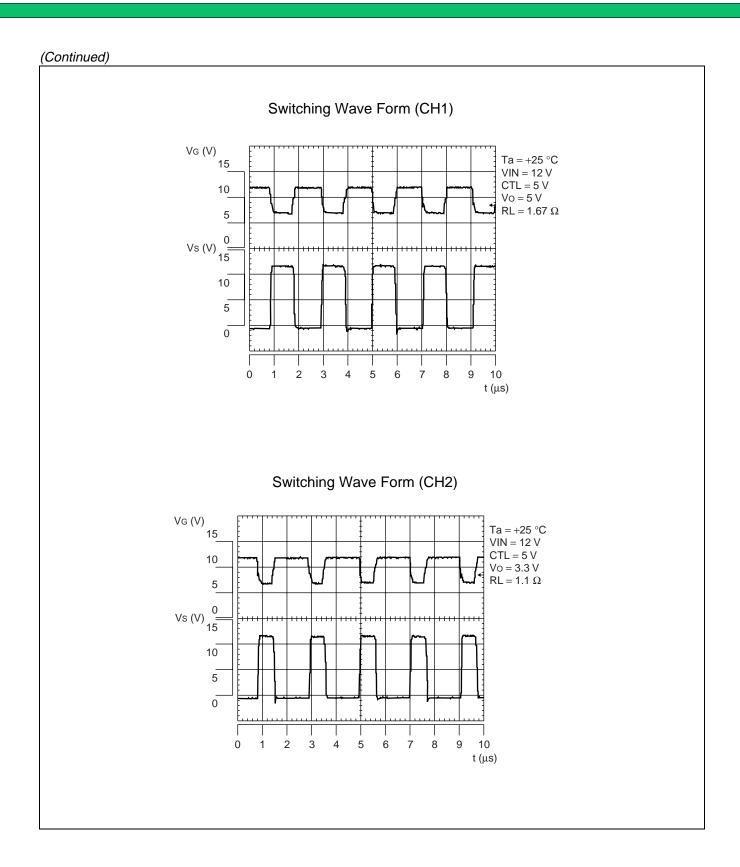
CH1

$$\begin{array}{ll} \text{ICLrms} & \geq \frac{ \left(V_{\text{IN}} - V_{\text{O}} \right) \, ton}{2 \sqrt{3 L}} \\ \\ & \geq \frac{ \left(19 - 3.3 \right) \, \times 0.174}{2 \sqrt{3} \times 15 \times 10^{-6} \times 500 \times 10^{3}} \\ \\ & \geq \frac{105.1 \, \text{mArms}}{ } \end{array}$$

■ REFERENCE DATA



(Continued)



■ USAGE PRECAUTION

• Printed circuit board ground lines should be set up with consideration for common impedance.

• Take appropriate static electricity measures.

- Containers for semiconductor materials should have anti-static protection or be made of conductive material.
- After mounting, printed circuit boards should be stored and shipped in conductive bags or containers.
- Work platforms, tools, and instruments should be properly grounded.
- Working personnel should be grounded with resistance of 250 k Ω to 1 M Ω between body and ground.

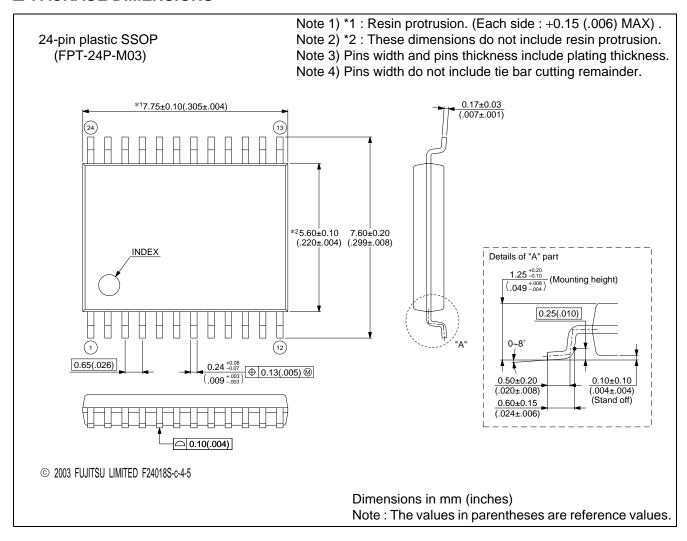
• Do not apply negative voltages.

The use of negative voltages below -0.3 V may create parasitic transistors on LSI lines, which can cause abnormal operation.

■ ORDERING INFORMATION

Part number	Package	Remarks
MB39A104PFV	24-pin plastic SSOP (FPT-24P-M03)	

■ PACKAGE DIMENSIONS



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